

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2832	temperature same current same resistance same (channel semiconductor)	USPAT	OR	OFF	2005/10/12 09:30
L2	137	1 same limit	USPAT	OR	OFF	2005/10/12 09:31
L3	64	2 same voltage	USPAT	OR	OFF	2005/10/12 09:35
L4	4	3 same (product or(ohms adj law) or $v=ir$)	USPAT	OR	OFF	2005/10/12 09:37
L5	4	3 same (product or(ohms adj law))	USPAT	OR	OFF	2005/10/12 09:37

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("6474762").PN.	USPAT; USOCR	OR	OFF	2005/10/12 12:04
L2	0	temperature near current near resistance near (channel semiconductor)	USPAT	OR	OFF	2005/10/12 12:05
L3	0	temperature near current near resistance near semiconductor	USPAT	OR	OFF	2005/10/12 12:05
L4	93624	resistance with temperature	USPAT	OR	OFF	2005/10/12 12:06
L5	1405	4 same current same (channel semiconductor)	USPAT	OR	OFF	2005/10/12 12:06
L6	728	5 same voltage	USPAT	OR	OFF	2005/10/12 12:06
L7	15	6 same (product (ohms adj law))	USPAT	OR	OFF	2005/10/12 12:07
S1	70325	(semiconductor adj switch) (transistor same switch)	USPAT	OR	OFF	2005/10/11 13:25
S2	1059	S1 same (DC adj power adj (supply source))	USPAT	OR	OFF	2005/10/11 13:25
S3	198	S2 same load	USPAT	OR	OFF	2005/10/11 13:25
S4	142	S3 same voltage	USPAT	OR	OFF	2005/10/11 13:25
S5	3	(("6166530") or ("6335577") or ("6552889")).PN.	USPAT; USOCR	OR	OFF	2005/10/11 12:36
S6	4602	(semiconductor adj switch)	USPAT	OR	OFF	2005/10/11 13:25
S7	117	S6 same (DC adj power adj (supply source))	USPAT	OR	OFF	2005/10/11 13:43
S8	37	S7 same load	USPAT	OR	OFF	2005/10/11 13:25
S9	30	S8 same voltage	USPAT	OR	OFF	2005/10/11 13:26
S10	17	S7 same (voltage with across)	USPAT	OR	OFF	2005/10/11 13:35
S11	913	S6 same (power adj (supply source))	USPAT	OR	OFF	2005/10/11 13:41
S12	265	S11 same load	USPAT	OR	OFF	2005/10/11 13:41
S13	46	S12 same (voltage with across)	USPAT	OR	OFF	2005/10/11 13:44
S14	24	S12 same (voltage with across with switch)	USPAT	OR	OFF	2005/10/11 13:36
S15	1	S12 same (voltage adj sensor)	USPAT	OR	OFF	2005/10/11 13:41
S16	37	S6 same (DC adj power adj (supply source)) same load	USPAT	OR	OFF	2005/10/11 13:43
S17	188	S12 same voltage	USPAT	OR	OFF	2005/10/11 13:45
S18	27	S17 same predetermined	USPAT	OR	OFF	2005/10/11 13:50
S19	81000	semiconductor adj device	USPAT	OR	OFF	2005/10/11 13:53
S20	108	S19 same (DC adj power adj (supply source))	USPAT	OR	OFF	2005/10/11 13:51
S21	28	S20 same load	USPAT	OR	OFF	2005/10/11 13:51

S22	18	S21 same voltage	USPAT	OR	OFF	2005/10/11 13:51
S23	5	S22 same predetermined	USPAT	OR	OFF	2005/10/11 13:51
S24	7482	(semiconductor adj device) same protect\$	USPAT	OR	OFF	2005/10/11 13:53
S25	7	S24 same (DC adj power adj (supply source))	USPAT	OR	OFF	2005/10/11 13:57
S26	3	S25 same load	USPAT	OR	OFF	2005/10/11 13:54
S27	3	S26 same voltage	USPAT	OR	OFF	2005/10/11 13:55
S28	1	S27 same predetermined	USPAT	OR	OFF	2005/10/11 13:54
S29	69056	(semiconductor adj switch) FET MOSFET	USPAT	OR	OFF	2005/10/11 13:57
S30	6161	S29 same protect\$	USPAT	OR	OFF	2005/10/11 13:57
S31	1016	S30 same (power adj (supply source))	USPAT	OR	OFF	2005/10/11 14:01
S32	173	S31 same DC	USPAT	OR	OFF	2005/10/11 14:01
S33	229	S31 same load	USPAT	OR	OFF	2005/10/11 14:02
S34	0	S33 same (voltage adj sensor)	USPAT	OR	OFF	2005/10/11 14:14
S35	165	S33 same voltage	USPAT	OR	OFF	2005/10/11 14:02
S36	25	S35 same predetermined	USPAT	OR	OFF	2005/10/11 14:02
S37	16	S30 same (voltage adj sensor)	USPAT	OR	OFF	2005/10/11 14:17
S38	4369	voltage with semiconductor with predetermined	USPAT	OR	OFF	2005/10/11 14:18
S39	502	S38 same across	USPAT	OR	OFF	2005/10/11 14:18
S40	1	S38 same (semiconductor adj switch)	USPAT	OR	OFF	2005/10/11 14:21
S41	0	(cut shut) with voltage with semiconducotr with (supply source)	USPAT	OR	OFF	2005/10/11 14:25
S42	56335	transistor same (power adj (source supply))	USPAT	OR	OFF	2005/10/11 14:26
S43	10022	S42 same load	USPAT	OR	OFF	2005/10/11 14:26
S44	837	S43 same voltage same predetermined	USPAT	OR	OFF	2005/10/11 14:28
S45	83	S44 same protect\$	USPAT	OR	OFF	2005/10/11 15:16
S46	483	transistor near sensor	USPAT	OR	OFF	2005/10/11 15:22
S47	0	S46 near drop near threshold near voltage	USPAT	OR	OFF	2005/10/11 15:22
S48	40	transistor near drop near threshold	USPAT	OR	OFF	2005/10/11 15:26
S49	978	transistor near drop near voltage	USPAT	OR	OFF	2005/10/11 15:28
S50	0	transistor near drop near voltage near across	USPAT	OR	OFF	2005/10/11 15:27
S51	0	semiconductor near drop near voltage near across	USPAT	OR	OFF	2005/10/11 15:27

S52	1313	(voltage adj drop) near (transistor semiconductor)	USPAT	OR	OFF	2005/10/11 15:29
S53	843	"53" near predetermined	USPAT	OR	OFF	2005/10/11 15:29
S54	0	S52 near predetermined	USPAT	OR	OFF	2005/10/11 15:29
S55	2	S52 near (exceed exceeds)	USPAT	OR	OFF	2005/10/11 15:30
S56	1	("5731686").PN:	USPAT; USOCR	OR	OFF	2005/10/12 11:25
S57	832	channel near temperature	USPAT	OR	OFF	2005/10/12 08:47
S58	5	S57 near resistance	USPAT	OR	OFF	2005/10/12 08:48
S59	29	(channel adj temperature) same resistance	USPAT	OR	OFF	2005/10/12 08:48